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Introduction

Chirality is one of the most essential characteristics in living organisms and nature universally,^{1,2} and is necessary for complex biometric recognition and replication functions in living systems.³ An object is chiral when its mirror image cannot be superimposed with the original object.4,5 In materials science, chirality is often used to represent an important noncentrosymmetric structural feature that can be obtained by introducing chiral molecules.6 The introduction of chirality usually brings optical rotation,⁷ circular dichroism (CD),⁸ and circularly polarized light (CPL) emission4,9 in materials. In some cases, it can even induce non-centrosymmetry-related properties such as the bulk photovoltaic effect (BPVE),¹⁰⁻¹² second-harmonic generation,13-15 piezoelectricity,16,17 ferroelectricity,18-20 Rashba splitting,^{21,22} and topological quantum properties.²³ Although organic chiral materials exhibiting strong chiral activity in the near-ultraviolet region are widely available, the charge transfer capability of actual polarized optoelectronic devices is poor,5 and there is an urgent need to develop new chiral lead iodide hybrids with strong absorption capacity and a broad light spectrum.

Chiral three-dimensional organic-inorganic lead iodide hybrid semiconductors†

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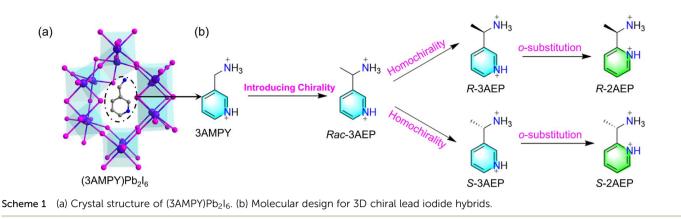
Chiral hybrid metal halides (CHMHs) have received a considerable amount of attention in chiroptoelectronics, spintronics, and ferroelectrics due to their superior optoelectrical properties and structural flexibility. Owing to limitations in synthesis, the theoretical prediction of room-temperature stable chiral three-dimensional (3D) CHFCINH₃Pbl₃ has not been successfully prepared, and the optoelectronic properties of such structures cannot be studied. Herein, we have successfully constructed two pairs of chiral 3D lead iodide hybrids (*R/S/Rac*-3AEP)Pb₂I₆ (*3R/S/Rac*, 3AEP = 3-(1-aminoethyl)pyridin-1-ium) and (*R/S/Rac*-2AEP)Pb₂I₆ (*2R/S/Rac*, 2AEP = 2-(1-aminoethyl)pyridin-1-ium) through chiral introduction and ortho substitution strategies, and obtained bulk single crystals of *3R/S/Rac*. The *3R/S* exhibits optical activity and bulk photovoltaic effect induced by chirality. The *3R* crystal device exhibits stable circularly polarized light performance at 565 nm with a maximum anisotropy factor of 0.07, responsivity of 0.25 A W⁻¹, and detectivity of 3.4 × 10¹² jones. This study provides new insights into the synthesis of chiral 3D lead halide hybrids and the development of chiral electronic devices.

Metal halide hybrids, especially three-dimensional (3D) lead halide hybrids, have attracted great attention from researchers due to their excellent properties such as long carrier diffusion lengths,24-27 high carrier mobility,28,29 bandgap tunability,30 low trap densities,³¹ and high power conversion efficiency.³² The continuous breakthrough of the record photoelectric conversion record efficiency of single-junction lead halide hybrid solar cells has completely triggered the research boom of lead halide hybrid semiconductor materials.³² In addition, the structural diversity of organic cations in metal halides and the ionic properties of the inorganic framework make it possible to directly obtain chiral metal halides by introducing chiral cations. The introduction of chirality extends the excellent optoelectronic properties of metal halides to the field of chiral electronics, greatly expanding their application range and potential.^{4,33-35} Tang et al. reported a CPL detector based on a 1D $(R/S-PEA)PbI_3$ (PEA = phenethylammonium) structure, providing an effective method for the direct detection of CPL.³⁶ In 2019, Xiong et al. reported a pair of 2D chiral metal halide ferroelectrics $(R/S-CMBA)_2PbI_4$ (CMBA = 1-(4-chlorophenyl) ethylammonium).¹⁶ In 2020, Fu et al. reported the chiral ferroelectric $(R/S-3-FPRD)MnBr_3$ (3-FPRD = 3-fluoropyrrolidinium) with CPL emission properties; the luminescence asymmetry factor $|g_{lum}|$ is 6.1 × 10⁻³, and the photoluminescence quantum yield is 28.31%.37 Recently, Luo et al. constructed a pair of 3D chiral lead chloride hybrids (R/S-BPEA)EA₆Pb₄Cl₁₅ (BPEA = 1-4bromophenylethylammonium, EA = ethylammonium,³⁸ but due to the large cavity of their inorganic framework, their band gap is much larger than that of the reported 3D lead iodide

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hybrids.³⁹⁻⁴¹ However, until now, the chiral 3D lead iodide hybrids, which are theoretically predicted to be both thermodynamically and kinetically stable, have been rarely reported.²

Inspired by the organic-to-inorganic structural chirality transfer effect in chiral hybrid metal halides (CHMHs), we know that the introduction of chiral cations into the inorganic framework is the most direct and effective way to obtain CHMHs.⁵ Here, using the 3D lead iodide hybrid (3AMPY)Pb₂I₆ (3AMPY = 3-aminomethylpyridinium) as a template and introducing methyl and ortho substitution strategies in the divalent cation 3AMPY (Scheme 1a and b), two pairs of 3D chiral lead iodide hybrids (R/S-3AEP)Pb₂I₆ (3R/S/Rac, 3AEP = 3-(1aminoethyl)pyridin-1-ium) and $(R/S-2-AEP)Pb_2I_6$ (2R/S/Rac, 2AEP = 2-(1-aminoethyl)pyridin-1-ium) were synthesized, and bulk single crystals of 3R/S/Rac were obtained. We find the BPVE under white-light irradiation in 3R/S. The sign of zerobias photocurrent is altered depending on the configuration of the chirality R/S-3AEP. 3R/S also exhibits chiroptical properties and the Rashba effect with a Rashba coefficient ($\alpha_{\rm R}$) of 0.23 eV Å.

Results and discussion

Synthesis

We first referred to the synthesis method of (3AMPY)Pb₂I₆ reported in the literature (Fig. 1a)³⁹ and tried to use a 4:1 ratio of Pb²⁺ to the 3-AMPY starting material to obtain the chiral 3D metal halide hybrids. However, we did not obtain the desired 3D structure, but only a 2D structure under this condition. We guessed that the introduction of the methyl group may increase the steric hindrance, leading to an increase in the synthesized energy barrier. This may be overcome by increasing the proportion of Pb^{2+} . We then investigated the 5 : 1, 6 : 1, and 7 : 1 ratios of Pb²⁺ and the organic cation (Fig. 1b and c), and found that 3D structures can be obtained at 6:1 and higher ratios (Fig. 1c). However, a similar 3D lead iodide hybrid (M₂pda)Pb₂I₆ $(M_2pda = N-methyl-1, 3-propanediammonium)$ was found to be synthesized with a 3:1 ratio of starting materials,⁴¹ which inspired us that reaction conditions play an important role in the structural dimensions of metal halides, especially the proportion of starting materials and reaction temperature.

Two pairs of chiral 3D lead iodide compounds 2R/S/Rac and 3R/S/Rac were thus synthesized with bivalent chiral cations as

shown in Scheme 1b and Fig. S1.[†] Red block single crystals of 3R/S/Rac with a size of $5 \times 3 \times 3.0 \text{ mm}^3$ were obtained by slowly evaporating the solutions at 80 °C (Fig. 1c and S2[†]). However, due to the solubility of 2R/S/Rac and growth temperature constraints, a pure phase cannot be obtained, so the structures and properties of 3R/S/Rac are studied below.

The purity of the phase was confirmed by powder X-ray diffraction (Fig. S3†). The infrared spectrum of the compounds shows several vibrational peaks at 1480, 3000, and 3500 cm⁻¹, which are attributed to the vibration absorption of N–H, C–H, C=C, and C=N bonds, respectively, demonstrating the successful introduction of the *Rac/R/S*-3AEP divalent cation into the 3D inorganic lattices (Fig. S4†). Thermogravimetric analysis shows the thermal stability of **3***R*/*S*/*Rac* up to about 575 K (Fig. S5†), comparable to that of (M₂pda)Pb₂I₆⁴¹and (Dmpz) Pb₂I₆.⁴⁰

Crystal structure

Single-crystal XRD analysis shows that 3Rac crystallizes in the centrosymmetric space group *Cmca*, with cell parameters a =12.9279(4) Å, b = 18.7439(6) Å, c = 17.6358(5) Å, and $\alpha = \beta = \gamma =$ 90° (Table 1). In the 3Rac structure, a mirror passes through the cation to result in a static disorder of the substituents of the pyridine ring (Fig. S6[†] and 1b). Due to the existence of the structural phase transition in 3R/S, we first analyze the structural characteristics of the low-temperature ordered state. Compounds 3S and 3R are all crystallized in the chiral space group $C222_1$ at 240 K with the cell parameters of a =12.9335(5) Å, b = 18.7439(8) Å, c = 17.6358(8) Å, and $\alpha = \beta = \gamma =$ 90° (Table 1). Due to the introduction of enantiomerically chiral cations, the crystal packing structures of the 3S and 3R exhibit mirror symmetry (Fig. 1e and f). To our knowledge, this is the first report of chiral 3D hybrid lead halides formed from lead halide octahedral dimers (Table S1[†]). The structure of 2R/S/Rac adopts the same space group as 3R/S/Rac (Table 1).

The basic structural motif of $(AEP)Pb_2I_6$ adopts a rare 3D lead iodide anion framework of AM_2I_6 , where A is the bulky cation template for the inorganic lead iodide framework. The crystal structure contains 3D inorganic lead iodide inorganic frameworks of corner- and edge-sharing PbI₆ octahedra with vacancies occupied by the 3AEP organic cations. Four edge-sharing dimers are connected by the corners of the individual layers to

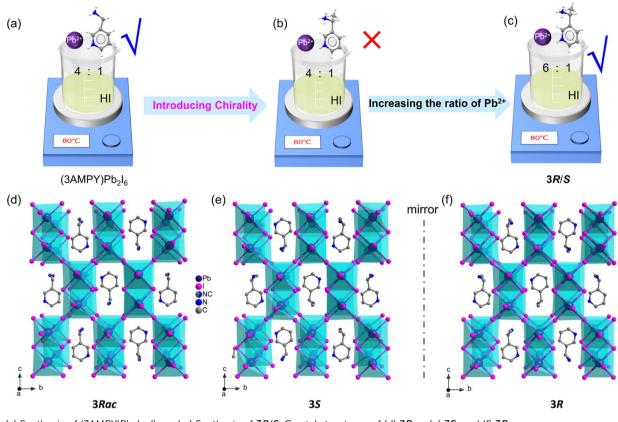


Fig. 1 (a) Synthesis of (3AMPY)Pb₂I₆. (b and c) Synthesis of 3*R*/*S*. Crystal structures of (d) 3*Rac*, (e) 3*S*, and (f) 3*R*.

form a continuous layer with rectangular voids extending along the *bc* crystal plane. The layers are stacked along the *a*-axis by angle-to-angle connections to form an anionic 3D inorganic framework (Fig. 1c and S7[†]). The rectangular void in the inorganic skeleton differs from the parallelogram void induced by the chain alkyl diamine in the (M₂pda)Pb₂I₆,⁴¹ which is caused by the template effect of the characteristic size and rigid shape of 3AEP. The asymmetric unit consists of one 3AEP divalent cation, two Pb ions, and six I ions (Fig. S8a⁺). The 3AEP cations are located in the plane of the layer, perpendicular to the stacking direction in the pores. They are bonded to the 3D inorganic framework by the hydrogen bond interaction of N-H…I and C-H…I, with the bond lengths of N-H…I ranging from 2.85 to 3.2 Å and C-H…I ranging from 3.93 to 4.16 Å (Fig. S8b and c⁺). Hirshfeld surface analysis reveals a predominant role of the hydrogen bonding interactions of H…I and additional van der Waals interactions of C…I between the cations and the I anions (Fig. S9[†]). Rich hydrogen bonding and van der Waals interactions promote effective chiral transfer of the chiral cations to the inorganic sublattices, with 21 screw axes crossing the corner-sharing octahedral bridging iodine atoms and twisted Pb-I planes along the a and c directions, respectively (Fig. S8d and Table S2[†]).

Structural phase transition properties

Structural properties were analyzed in detail by taking 3R as an example. The thermal properties of 3R during the structural phase transition were investigated. As shown in Fig. 2a, 3R

exhibited two pairs of obvious endothermic and exothermic peaks at 293/275 K (T_1) and 419/414 K (T_2) , indicating two reversible structural phase transitions. For the convenience of analysis, the phase below T_1 is referred to as the low temperature phase (LTP), the phase between T_1 and T_2 as the intermediate temperature phase (ITP), and the phase above T_2 as the high-temperature phase (HTP). At T_1 , there is a thermal hysteresis of 18 K with a phase transition centered at 284 K, while at T_2 the thermal hysteresis is only 5 K with a phase transition center of 417 K. The ΔH at T_1 is 5.88 kJ mol⁻¹ and that at T_2 is 0.71 kJ mol⁻¹. As can be seen from Fig. 2b, 3*Rac* does not undergo any structural phase transition in the corresponding temperature range. The temperature-dependent dielectric constant of 3R crystalline powder was measured. As shown in Fig. 2c, the dielectric anomalies occur in the process of temperature change at different test frequencies. An obvious step-type dielectric anomaly can be seen from the 1 MHz curve, which confirms the DSC test results (Fig. 2a).

When the temperature increased to 298 K, the compound underwent an order–disorder phase transition due to the disordered substituents on the pyridine ring. The ordered and disordered cationic terminal groups did not cause changes in the space group (cell parameters, a = 12.9629(5) Å, b = 18.7955(5) Å, c = 17.6714(8) Å, $\alpha = \beta = \gamma = 90^{\circ}$) (Tables S3 and S4†). However, the bond length and bond angle of the inorganic anion skeleton are extended and enlarged with increasing temperature, which is a typical effect of thermal expansion and contraction. With the further increase of temperature to 425 K, the whole cations in the

Table 1 Crystal and refinement data for compounds reported here

Compound	$(R-3AEP)Pb_2I_6$	$(S-3AEP)Pb_2I_6$	(Rac-3AEP)Pb ₂ I ₆
Formula	C ₇ H ₁₂ N ₂ Pb ₂ I ₆	C ₇ H ₁₂ N ₂ Pb ₂ I ₆	C ₇ H ₁₂ N ₂ Pb ₂ I ₆
Formula weight	1299.97	1299.97	1299.97
Crystal system	Orthorhombic	Orthorhombic	Orthorhombic
Space group	$C222_{1}$	$C222_{1}$	Cmca
a/Å	12.9493(3)	12.9335(5)	12.9279(4)
b/Å	18.7108(5)	18.7439(8)	18.7521(6)
c/Å	17.6439(5)	17.6358(8)	17.6600(5)
$\alpha, \beta, \gamma/^{\circ}$	90	90	90
$V/\text{\AA}^3$	4274.97(19)	4273.3(3)	4281.20(2)
Flack parameter	-0.016(16)	0.00(3)	—
R _{int}	0.038	0.066	0.083
$R_1^{a}/\mathrm{w}R_2^{b}\left(I > 2\sigma(I)\right)$	0.0606, 0.1713	0.0684, 0.1748	0.0561, 0.1520
R_1/wR_2 (all data)	0.0692, 0.1785	0.0900, 0.1865	0.0667, 0.1619
GOF	1.064	1.02	1.036
Compound	$(R-2AEP)Pb_2I_6$	(S-2AEP)Pb ₂ I ₆	(Rac-2AEP)Pb ₂ I ₆
Formula	C ₇ H ₁₂ N ₂ Pb ₂ I ₆	C ₇ H ₁₂ N ₂ Pb ₂ I ₆	C ₇ H ₁₂ N ₂ Pb ₂ I ₆
Formula weight	1299.97	1299.97	1299.97
Crystal system	Orthorhombic	Orthorhombic	Orthorhombic
Space group	C222 ₁	C2221	Стса
a/Å	12.9873(5)	12.9972(3)	12.9548(6)
b/Å	18.8387(7)	18.8397(7)	18.8648(9)
c/Å	17.5741(8)	17.5687(6)	17.6101(7)
$\alpha, \beta, \gamma/^{\circ}$	90	90	90
$V/\text{\AA}^3$	4299.7(3)	4301.9(2)	4303.7(3)
Flack parameter	0.006(8)	0.002(15)	—
R _{int}	0.0289	0.0593	0.0394
$R_1^{a}/\mathrm{w}R_2^{b}\left(I > 2\sigma(I)\right)$	0.0286, 0.0593	0.0681, 0.1653	0.0517, 0.1058
R_1/wR_2 (all data)	0.0361, 0.0612	0.0856, 0.1807	0.0762, 0.1151
GOF	0.974	1.005	1.107
^{<i>a</i>} $R_1 = \Sigma F_0 - F_c / F_0 $. ^{<i>b</i>} $wR_2 = [\Sigma w (F_0^2 - F_c^2)^2] / \Sigma w (F_0^2)^2]^{1/2}$.			

inorganic framework undergo a violent disorder, causing the space group to change to *C*222 with higher symmetry (cell parameters, a = 9.4786(5) Å, b = 17.723(10) Å, c = 6.5033(8) Å, and $\alpha = \beta = \gamma = 90^{\circ}$) (Tables S3 and S4†). In the HTP, there are three mutually perpendicular 2-fold axes passing through the 3-AEP cation (Fig. S10†), corresponding to the highly disordered state. The bond lengths and bond angles of the inorganic skeleton have further lengthened and become larger (Fig. 2e, g and i). The Pb–I–Pb bond angles belonging to the canonical angle shared bond have not yet reached the standard 180° (Table S5†), and there are still tiny distortions in the structure (Fig. 2i).

Semiconducting properties and the BPVE

DFT calculations were performed based on the 240 K crystal structure of 3R using the exchange–correlation functional PBE (Fig. 3a and b). Both the valence and conduction bands exhibit dispersion, but the degree of dispersion is smaller than that of CH₃NH₃PbI₃ due to the relatively lower octahedral edge-sharing connectivity in the structure.⁴² The data show that 3R is a direct bandgap semiconductor with a bandgap value of 2.04 eV at the *Y*-point without spin–orbit coupling (SOC) (Fig. 3a), and turns to an indirect one with a bandgap value of 1.48 eV due to the Rashba spin splitting effect (Fig. 3b). Our PBE density of states (DOS) data

show that Pb 6s and I 5p orbitals overlap to form the valence band maximum (VBM), and Pb 6p orbitals overlap to form the conduction band minimum (CBM), indicating that the energy band and semiconductor performance are mainly determined by the inorganic components (Fig. 3b). We find electronic states derived from the molecular sublattice ~ 0.4 eV above the conduction band minimum. Higher accuracy electronic-structure approaches such as hybrid functionals or many-body perturbation theory and the inclusion of thermal broadening effects might lead to the participation of these molecular electronic states in the conduction band edge. Ultraviolet-visible diffuse-reflectance spectra of 3R, 3S, and 3Rac are shown in Fig. 3c. There is significant absorption in the ultraviolet region, and the edge of the band extends into the visible light region near 600 nm. Based on the Kubelka–Munk equation,^{43,44} the optical bandgap value is estimated to be 2.13 eV (Fig. 3a), which is smaller than the bandgap of common 2D lead iodide semiconductor materials,45 and is comparable to that of chiral quasi-2D lead iodide hybrid (R/S- $MPA_{2}(MA)Pb_{2}I_{7}$ (MA = methylammonium, MPA = methylphenethylammonium) (~2.08 eV).10

The dark current and on/off ratio are the two main parameters that affect the optoelectronic properties of semiconductors. The dark current of the **3***R* single crystal device along the [100] direction in a dark environment is as low as 10^{-10} A (Fig. 3d and e), which is much lower than 10^{-7} A of MAPbI₃.⁴⁶ Under sunlight irradiation of 100 mW cm⁻², the photocurrent rapidly increases to 3.6×10^{-7} A, and the on/off ratio is greater than 4×10^3 , consistent with our previously reported results.⁴¹ The BPVE induced by chirality was observed in the *I*–*V* curve for the [001] parallel alignment with a zero-bias photocurrent with a short-circuit current $|I_{sc}|$ of ~0.37 nA and an open-circuit voltage $|V_{oc}|$ of ~0.11 V for both **3***R* and **3***S* (Fig. 3f). The I_{sc} and V_{oc} values are larger than those of reported quasi-2D CHMHs and (*R/S*-MPA)₂(MA)Pb₂I₇.¹⁰ No BPVE phenomenon was observed in **3***Rac* (Fig. 3f).

Chiroptical properties and the Rashba-Dresselhaus effect

The CD spectra of 3R and 3S were measured on the crystal powders. In the wavelength range of 200-580 nm, there is a clear CD signal at the edge of the absorption band and exciton peak at 565 nm, extending to 580 nm. The enantiomers show the same signal size but an opposite sign of the absorption peaks at 565 nm, a typical Cotton effect in the CD spectrum (Fig. 4a). In contrast, 3Rac has no characteristic absorption in the CD spectrum (Fig. 4a). At the same time, the UV-vis absorption spectra in the 200-580 nm range are consistent with the characteristic peaks of the CD absorption spectra (Fig. 3b). These results confirm the effective chiral transfer from the chiral cations to the inorganic sublattices. The calculated $g_{\rm CD}$ is 4.1 × 10⁻⁶ at 565 nm (Fig. 4b). Based on a 3*R* single crystal device (Fig. 4c), we investigated its response to 565 nm CPL. The anisotropy factor for photocurrent (g_{Iph}) is up to 0.08 at a bias of 5 V and at 0.17 mW cm⁻² (Fig. 4d). This is smaller than the reported low-dimensional CHMH detector $g_{\text{Iph}}^{22,36,47}$ and we speculate that is caused by the order-disorder motion of the cations at room temperature, as this reduces the efficiency of

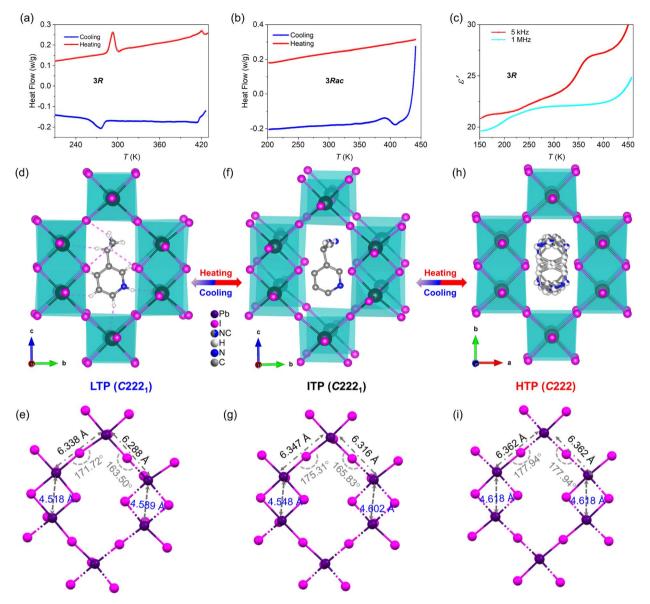


Fig. 2 (a) DSC curves of 3*R*. (b) DSC curves of 3*Rac*. (c) Dielectric transition of 3*R*. Crystal structure of 3*R* in the ordered LTP (d), and disordered ITP (f), HTP (h) and the corresponding connection motifs (e, g, and i).

chiral transfer from the chiral cations to the inorganic framework,⁴⁸ thereby reducing the $g_{\rm iph}$. Although the chiral optical properties of our materials are still unsatisfactory due to the disorder of the cations, it can be foreseen that the introduction of room-temperature ordered chiral cations into 3D lead iodide structures will greatly improve the chiroptical properties of such materials. In addition to the CPL sensing, the device also exhibits good photoresponses. The $I_{\rm ph}/I_{\rm dark}$ ratio at 565 nm was obtained by measuring the *I–V* curves in the dark and under different illumination intensities from 0–0.17 mW cm⁻² (Fig. 4e). The measured responsivity and specific detectivity without frequency modulation are 0.25 A W⁻¹ and 3.2×10^{12} jones, respectively (Fig. 4f). These merits indicate that the single-crystal device is a good candidate for CPL detection. The combination of heavy element Pb and noncentrosymmetric structures (chirality) leads to the Rashba–Dresselhaus (RD) spin splitting effect. The possible existence of RD spin splitting is verified by first-principles calculation. As shown in Fig. 5a and b, band splitting occurs at the *Y* point at the base of the conduction band (Fig. 5b). The RD splitting coefficient is defined as $\alpha_{RD} = 2E_{RD}/\Delta k$, where E_{RD} is the energy splitting and Δk is the momentum shift. Fig. 5b shows that the E_{RD} along the Γ –*Y* path is 3 meV, the Δk is 0.0285 Å⁻¹, and the α_{RD} of the CBM is 0.21 eV Å. The E_{RD} along the *Y*–*C*₀ path is 0.5 meV, the Δk is 0.00424 Å⁻¹, and the α_{RD} of the CBM is 0.23 eV Å, which is smaller than that of 2D chiral ferroelectric (*R*-3AMP)PbBr₄²² and comparable to that of the polar quasi-2D lead iodide hybrid (IBA)₂(EA)₂Pb₃I₁₀ (IBA = 4-isopropylbenzylammonium, EA = ethylammonium).⁴⁹ Due to the different contributions of Pb and I elements to the CBM and

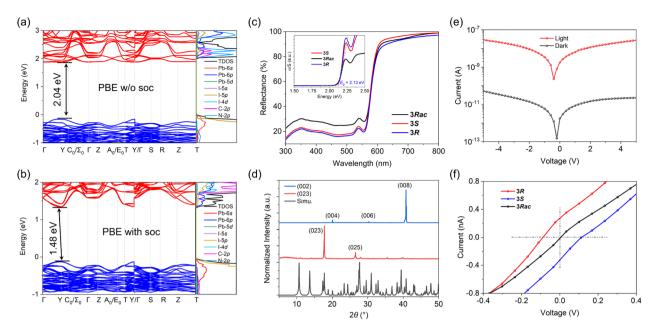


Fig. 3 (a) DFT-PBE and (b) DFT-PBE + SOC band structures and projected density of states (PDOS) of 3R. (c) UV-vis diffuse-reflectance spectra of 3R/S/Rac. Inset: optical bandgap derived from the Kubelka–Munk function based on diffuse-reflectance data. (d) PXRD patterns of the single crystal were recorded from the (023) and (001) planes. (e) I-V curves recorded in the dark and under 100 mW cm⁻² illumination along the [100]. (f) Bulk photovoltaic effect of 3R/S.

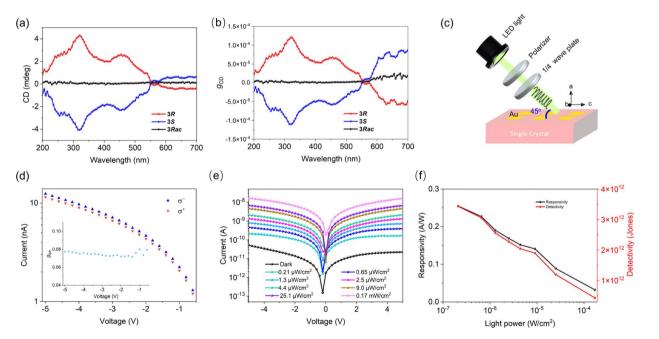


Fig. 4 (a) CD and (b) g_{CD} spectra of 3R/S and 3Rac. (c) Device architecture for the CPL detection of 3R. (d) I-V curves of the 3R photodetector under R-CPL and L-CPL illumination at 565 nm with an intensity of 0.17 mW cm⁻², as well as the calculated g_{Iph} . (e) I-V curves under different illumination intensities at 565 nm; (f) power intensity dependence of R and D^* at 565 nm.

VBM, the $\alpha_{\rm RD}$ of the VBM is much less obvious than that of the CBM (about 0.04 eV Å). The difference in $\alpha_{\rm RD}$ values along the Γ -Y and Y- C_0 paths indicates the anisotropy of the band splitting (Fig. 5b). The calculated RD effect was also verified by CPL excited photoluminescence measurements.⁵⁰ The opposite fluorescence

intensity difference between **3***R* and **3***S* under the excitation of CPL with different helicity further indicates that the existence of RD splitting causes them to produce spin splitting bands with opposite optical helicity (Fig. S11†).

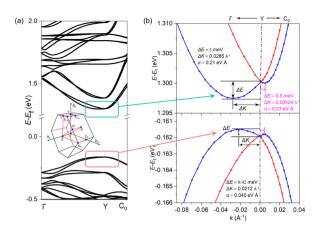


Fig. 5 (a) DFT-PBE + SOC band structure of 3R along selected k paths (inset is the Brillouin zone with high symmetry k points). (b) Rashba–Dresselhaus splitting.

Conclusions

In conclusion, we have constructed two pairs of 3D chiral leadiodide hybrids (R/S-3AEP)Pb₂I₆ and (R/S-2AEP)Pb₂I₆ through chiral introduction and *ortho* substitution strategies and obtained bulk single crystals of 3R/S. These 3D CHMHs exhibit good circular dichroism, CPL detection performance, and the RD effect. Meanwhile, the crystal device shows excellent photodetection performances in terms of the on/off ratio, responsivity, detectivity, and bulk photovoltaic effect for self-power detection. This provides new research ideas and materials for the research and development of chiroptics and spintronics.

Data availability

The data supporting this article have been included as part of the ESI.†

Author contributions

Chang-Chun Fan: conceptualization, data curation, formal analysis, investigation, methodology, validation and writingoriginal draft; Cheng-Dong Liu: data curation and methodology; Bei-Dou Liang: visualization and formal analysis; Tong-Yu Ju supervision; Wei Wang: investigation; Ming-Liang Jin: formal analysis; Chao-Yang Chai: supervision; Wen Zhang: conceptualization, data curation, funding acquisition, resources, supervision, software and writing-review & editing.

Conflicts of interest

There are no conflicts to declare.

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